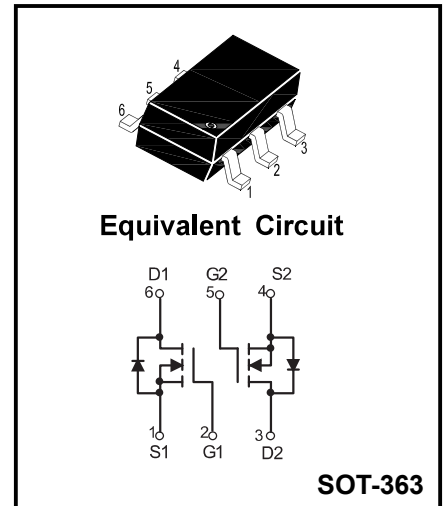


Plastic-Encapsulate MOSFETs



Dual N-channel MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
50V	3.5Ω@10V	220mA
	6Ω@4.5V	

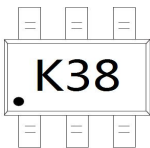
FEATURE

- ◆ High density cell design for low RDS(ON)
- ◆ Voltage controlled small signal switch
- ◆ Rugged and reliable
- ◆ High saturation current capability

APPLICATION

- ◆ Load Switch for Portable Devices
- ◆ DC/DC Converter

MARKING



MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	50	V
Continuous Gate-Source Voltage	V_{GSS}	±20	
Continuous Drain Current	I_D	0.22	A
Power Dissipation	P_D	0.3	W
Thermal Resistance from Junction to Ambient	$R_{θJA}$	417	°C/W
Operating Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55 ~ +150	

Ta=25°C unless otherwise specified

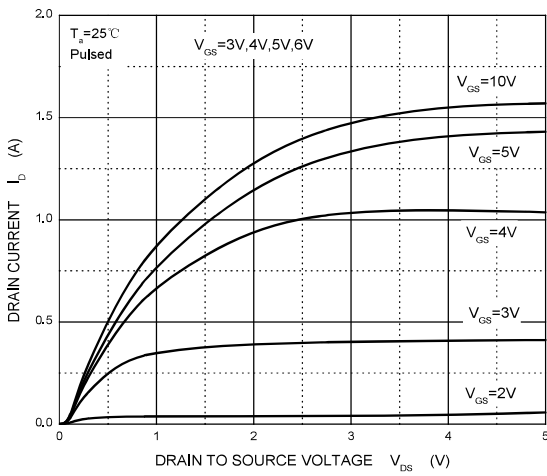
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	50			V
Gate-body leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$			± 500	nA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 50V, V_{GS} = 0V$			0.5	μA
		$V_{DS} = 30V, V_{GS} = 0V$			100	nA
On characteristics						
Gate-threshold voltage (note 1)	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 1mA$	0.80		1.50	V
Static drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 0.22A$			3.50	Ω
		$V_{GS} = 4.5V, I_D = 0.22A$			6	
Forward transconductance (note 1)	g_{FS}	$V_{DS} = 10V, I_D = 0.22A$	0.12			S
Dynamic characteristics (note 2)						
Input capacitance	C_{iss}	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$		27		pF
Output capacitance	C_{oss}			13		
Reverse transfer capacitance	C_{rss}			6		
Switching characteristics						
Turn-on delay time (note 1,2)	$t_{d(on)}$	$V_{DD} = 30V, V_{DS} = 10V, I_D = 0.29A, R_{GEN} = 6\Omega$			5	ns
Rise time (note 1,2)	t_r				18	
Turn-off delay time (note 1,2)	$t_{d(off)}$				36	
Fall time (note 1,2)	t_f				14	
Drain-source body diode characteristics						
Body diode forward voltage (note 1)	V_{SD}	$I_S = 0.44A, V_{GS} = 0V$			1.4	V

Notes:

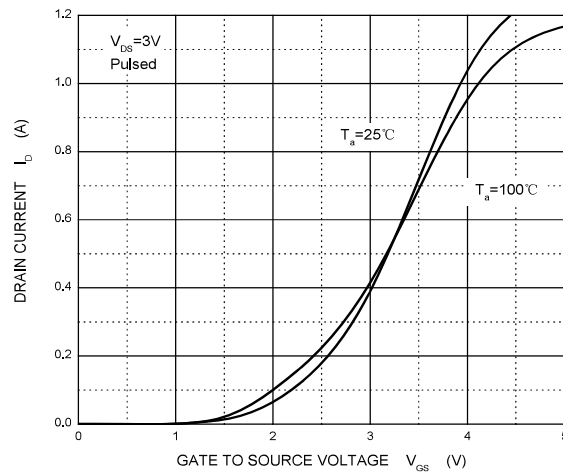
1. Pulse Test ; Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
2. These parameters have no way to verify.

Typical Characteristics

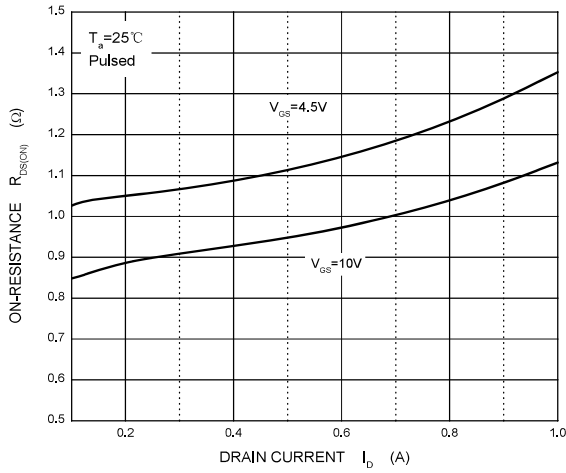
Output Characteristics



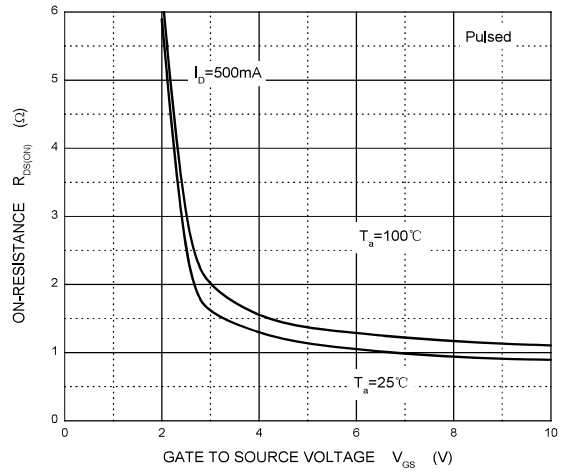
Transfer Characteristics



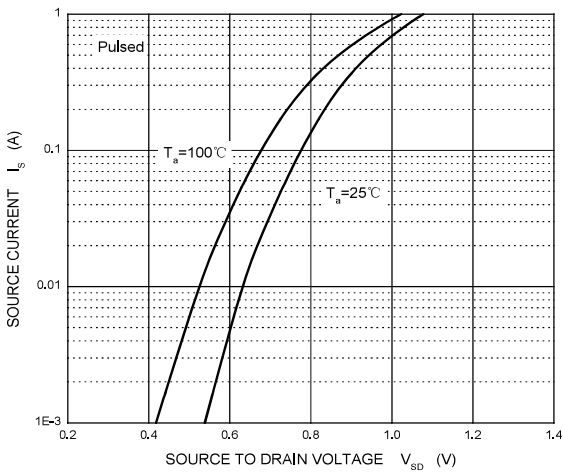
$R_{DS(ON)}$ — I_D



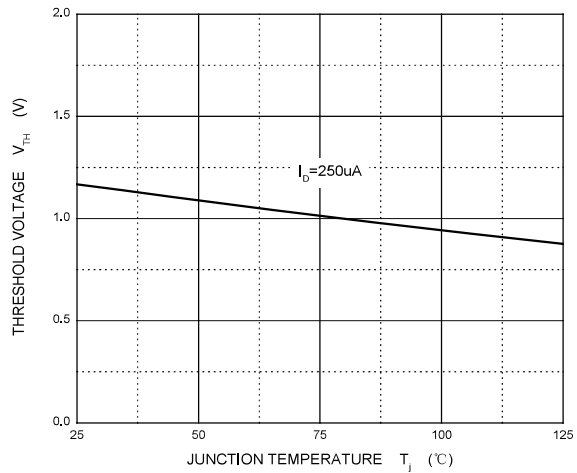
$R_{DS(ON)}$ — V_{GS}



I_S — V_{SD}

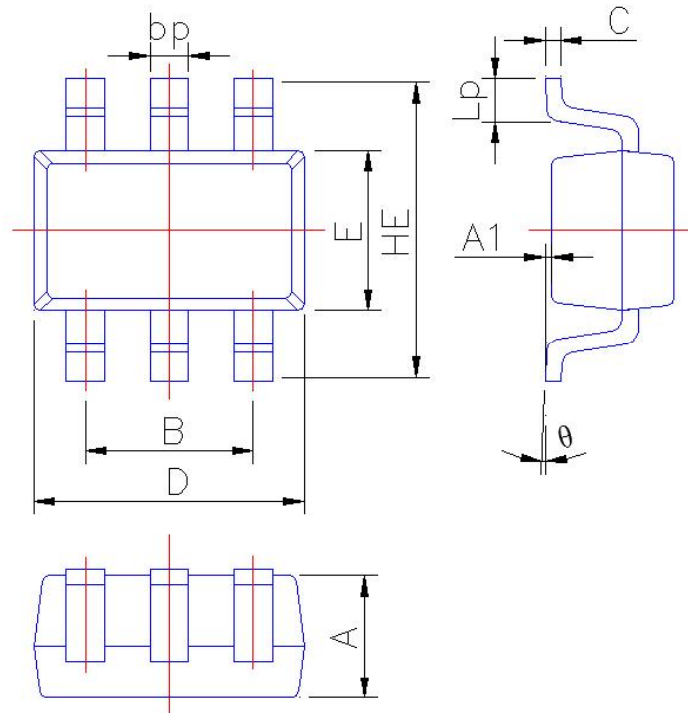


Threshold Voltage



Package Outline SOT-363

Plastic surface mounted package; 3 leads



Symbol	Dimension in Millimeters	
	Min	Max
A	0.90	1.00
A1	0.010	0.100
B	1.20	1.40
bp	0.25	0.45
C	0.09	0.15
D	2.00	2.20
E	1.15	1.35
HE	2.15	2.55
Lp	0.25	0.46
θ	0°	6°

Summary of Packing Options

Package	Package Description	Packing Quantity	Industry Standard
SOT-363	Tape/Reel, 7" reel	3000	EIA-481-1